





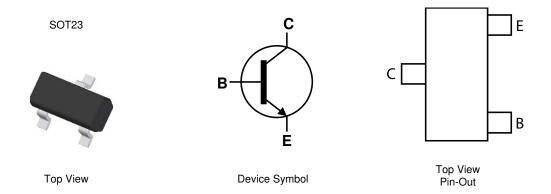
#### 30V NPN MEDIUM POWER TRANSISTOR IN SOT23

#### **Features**

- BV<sub>CEO</sub> > 30V
- I<sub>C</sub> = 1A high Continuous Collector Current
- I<sub>CM</sub> Up to 4A Peak Pulse Current
- Excellent h<sub>FE</sub> Characteristics Up To 4A
- R<sub>SAT</sub> = 175mΩ @ 1A for a Low Equivalent On-Resistance
- Low Saturation Voltage < 300mV @ 1A</li>
- 500mW Power Dissipation
- Complementary PNP Type: FMMT589
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

- Case: SOT-23
- Case material: Molded Plastic. "Green" Molding Compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 <a>©3</a>
- Weight: 0.008 grams (Approximate)



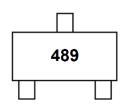
### **Ordering Information** (Note 4)

Product	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
FMMT489TA	489	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## Marking Information



489 = Product Type Marking Code





### **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	50	V
Collector-Emitter Voltage	V <sub>CEO</sub>	30	V
Emitter-Base Voltage	V <sub>EBO</sub>	7	V
Continuous Collector Current	Ic	1	Α
Peak Pulse Current	I <sub>CM</sub>	4	Α
Base Current	I <sub>B</sub>	200	mA

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P <sub>D</sub>	500	mW
Thermal Resistance, Junction to Ambient (Note 5)	R <sub>eJA</sub>	250	°C/W
Thermal Resistance, Junction to Lead (Note 6)	R <sub>eJL</sub>	197	°C/W
Operating and Storage Temperature Range	$T_{J}, T_{STG}$	-55 to +150	°C

### ESD Ratings (Note 7)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	≥ 4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	С

Notes:

<sup>5.</sup> For a device mounted with the collector lead on 15mm X 15mm 1oz weight copper that is on a single-sided FR4 PCB; device is measured under still air

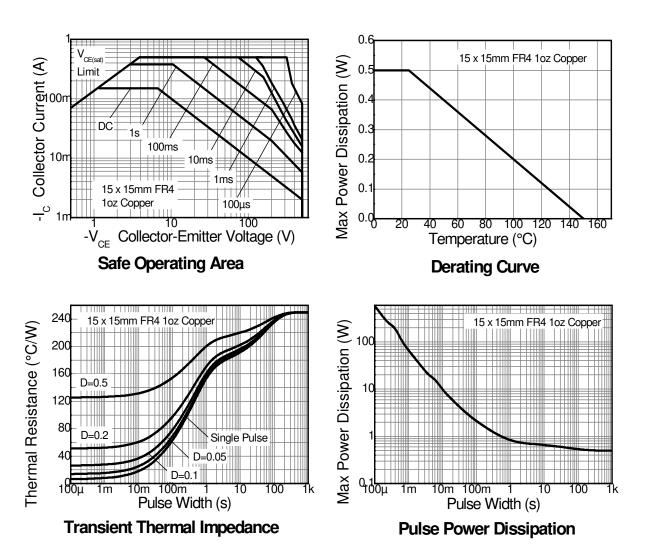
conditions whilst operating in a steady-state.

6. Thermal resistance from junction to solder-point (at the end of the collector lead).

7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



## **Thermal Characteristics and Derating Information**







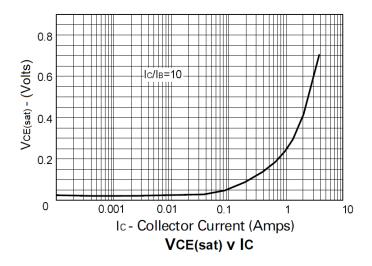
## **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

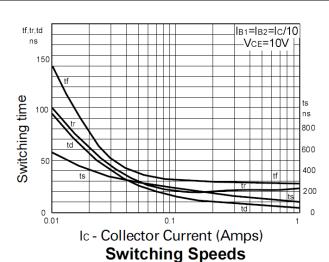
Characteristic	Symbol	Min	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	50		V	I <sub>C</sub> = 100 μA
Collector-Emitter Breakdown Voltage (Note 8)	BV <sub>CEO</sub>	30		V	I <sub>C</sub> = 10 mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	7		V	I <sub>E</sub> = 100 μA
Collector-Base Cutoff Current	I <sub>CBO</sub>		100	nA	V <sub>CB</sub> = 30V
Emitter-Base Cutoff Current	I <sub>EBO</sub>		100	nA	V <sub>EB</sub> = 6V
Collector-Emitter Cutoff Current	I <sub>CES</sub>		100	nA	V <sub>CES</sub> = 30V
Static Forward Current Transfer Ratio (Note 8)	h <sub>FE</sub>	100 100 60 20	- 300 - -		$\begin{split} &I_{C} = 1 \text{mA},  V_{CE} = 2 V \\ &I_{C} = 1 \text{A},  V_{CE} = 2 V \\ &I_{C} = 2 \text{A},  V_{CE} = 2 V \\ &I_{C} = 4 \text{A},  V_{CE} = 2 V \end{split}$
Collector-Emitter Saturation Voltage (Note 8)	V <sub>CE(sat)</sub>		300 600	mV mV	I <sub>C</sub> = 1A, I <sub>B</sub> = 100mA I <sub>C</sub> = 2A, I <sub>B</sub> = 200mA
Base-Emitter Turn-On Voltage (Note 8)	V <sub>BE(on)</sub>		1.0	V	I <sub>C</sub> = 1A, V <sub>CE</sub> = 2V
Base-Emitter Saturation Voltage (Note 8)	V <sub>BE(sat)</sub>		1.1	V	I <sub>C</sub> = 1A, I <sub>B</sub> = 100mA
Output Capacitance	C <sub>obo</sub>		10	pF	V <sub>CB</sub> = 10V, f = 1MHz
Transition Frequency	f <sub>T</sub>	150		MHz	$V_{CE} = 10V$ , $I_C = 50$ mA, $f = 100$ MHz

Note: 8. Measured under pulsed conditions. Pulse width  $\leq 300 \mu s$ . Duty cycle  $\leq 2\%$ 

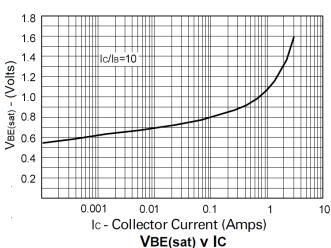


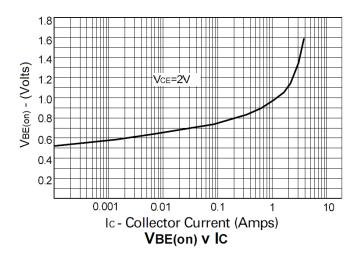
## Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)





200 160 VCE=2V 80 40 0 0.001 0.01 0.1 1 10 Ic - Collector Current (Amps) hFE v IC



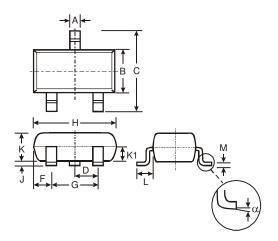






# **Package Outline Dimensions**

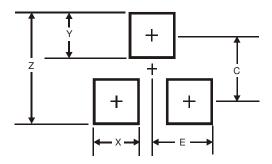
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



	SOT23					
Dim	Min	Max	Тур			
Α	0.37	0.51	0.40			
В	1.20	1.40	1.30			
С	2.30	2.50	2.40			
D	0.89	1.03	0.915			
F	0.45	0.60	0.535			
G	1.78	2.05	1.83			
Н	2.80	3.00	2.90			
J	0.013	0.10	0.05			
K	0.903	1.10	1.00			
K1	-	-	0.400			
L	0.45	0.61	0.55			
M	0.085	0.18	0.11			
α	0°	8°	-			
All Dimensions in mm						

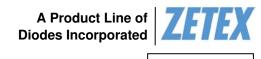
## **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)		
Z	2.9		
Х	0.8		
Υ	0.9		
С	2.0		
Е	1.35		





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